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AUG 29 2005

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE****Applicant(s):** Diane C. Boyd, et al.**Examiner:** Patricia Ann George**Serial No:** 10/725,848**Art Unit:** 1765**Filed:** December 2, 2003**Docket:** YOR920030335US1 (16900)**For:** ULTRA-THIN Si MOSFET DEVICE  
STRUCTURE AND METHOD OF  
MANUFACTURE**Dated:** August 29, 2005**Confirmation No.:** 3237Mail Stop Amendment  
Commissioner for Patents  
United States Patent Office  
Alexandria, VA 23313-1450**RESPONSE UNDER 37 C.F.R. §§1.111 AND 1.143**

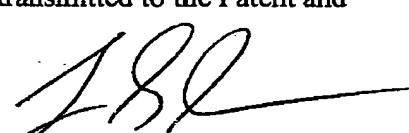
Sir:

In response to the Office Action dated August 12, 2005, applicants provisionally elect, without traverse, the subject matter of Group I, i.e., Claims 1-27 for continued prosecution in the above-identified patent application.

**CERTIFICATION OF FACSIMILE TRANSMISSION**

I hereby certify that this paper is being facsimile transmitted to the Patent and Trademark Office on the date shown below.

Dated: August 29, 2005

  
 Leslie S. Szivos
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